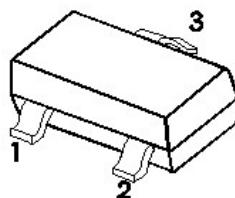
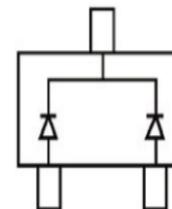
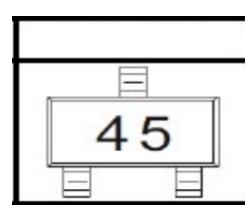


**特征 Features**
**SOT-23**


- 大电流承受能力。High Current Capability
- 正向压降低。Low Forward Voltage Drop
- 开关速度快。Extremely Fast Switching Speed

**机械数据 Mechanical Data**

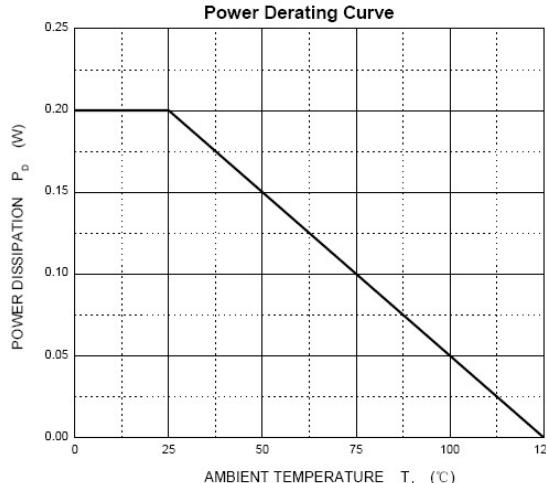
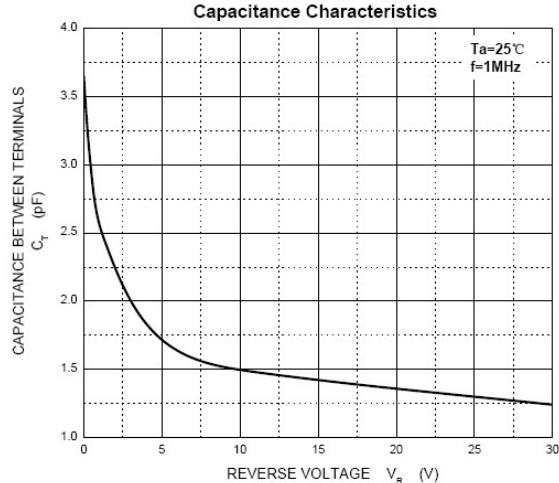
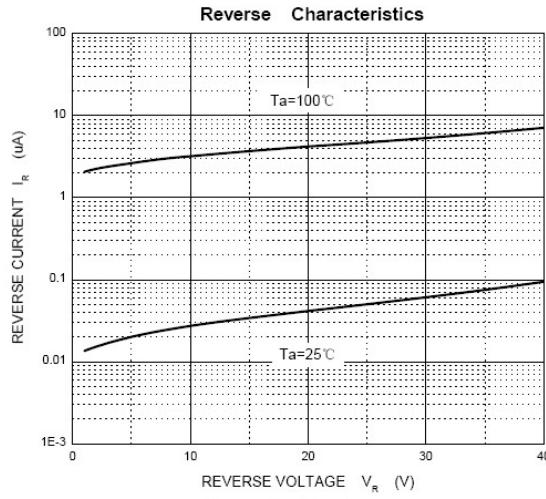
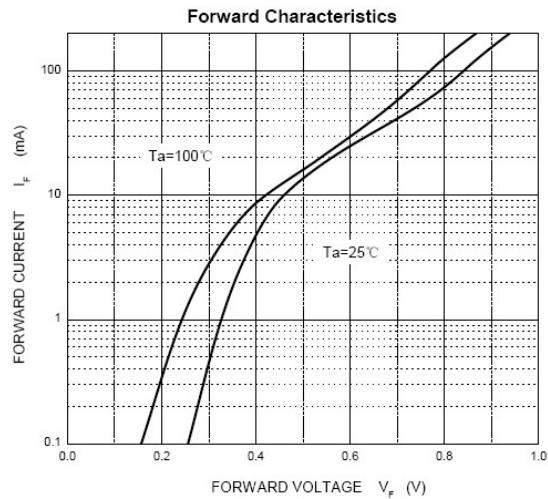
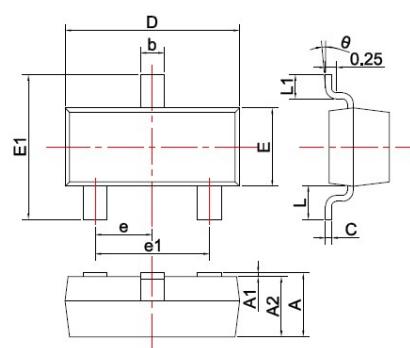
- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any


**MARKING: 45**
**极限值和温度特性(TA = 25°C 除非另有规定)**
**Maximum Ratings & Thermal Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	界限 Limit	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	VRRM	40	V
最大直流阻断电压 Maximum DC blocking voltage	VDC	40	V
最大正向平均整流电流 Maximum average forward rectified current	IFM	200	mA
典型热阻 Typical thermal resistance	R <sub>θJA</sub>	500	°C/W
功率消耗 Power Dissipation	PD	200	mW
结温 Junction Temperature	T <sub>j</sub>	125	°C
存储温度 Storage temperature range	T <sub>STG</sub>	-50-+150	°C

**电特性 (TA = 25°C 除非另有规定)**
**Electrical Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified).

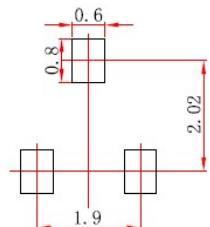
参数 Parameters	符号 Symbol	测试条件 Test conditions	Min	Typ	Max	单位 Unit
最大正向电压 Maximum forward voltage	VF1	IF = 1mA			380	mV
	VF2	IF = 40mA			1000	
最大反向电压 Maximum reverse breakdown voltage	VR	IR=10uA	40			V
最大反向电流 Maximum reverse current	IR	VR=30V			200	nA
典型结电容 Type junction capacitance	CD	VR = 0V, f = 1MHz			5	pF
反向恢复时间 Reverse Recovery time	trr	IF=IR=10mA Irr=1XIR, RL=100 Ω			5	ns

**Typical Characteristics**

**SOT-23 PACKAGE OUTLINE** Plastic surface mounted package


SYMBOL	DIMENSIONS	
	MIN	MAX
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.060	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950 (TYP)	
e1	1.800 (MIN)	2.000 (MAX)
L	0.550 (REF)	
L1	0.300 (MIN)	0.500 (MAX)
$\theta$	0° (MIN)	8° (MAX)

Unit: mm

焊盘设计参考 Precautions: PCB Design(Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs)



## Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.



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ChipNobo Co., Ltd

BAS40-05-7-F-CN

SOT-23 Plastic-Encapsulate  
Schottky Barrier Diode

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